

DIODE ARRAY PRODUCT SPECIFICATION

MONOLITHIC AIR ISOLATED DIODE ARRAY

FEATURES:

- HERMETIC CERAMIC PACKAGE
- $B_V > 60V$ at $10\mu A$
- $I_r < 100nA$ at $40V$
- $C < 8.0 pF$

Absolute Maximum Ratings:

Symbol	Parameter	Limit	Unit
VBR(R) *1 *2	Reverse Breakdown Voltage	60	Vdc
IO *1 *3	Continuous Forward Current	300	mAdc
IFSM *1	Peak Surge Current (tp= 1/120 s)	500	mAdc
PT1 *4	Power Dissipation per Junction @ 25°C	400	mW
PT2 *4	Power Dissipation per Package @ 25°C	600	mW
Top	Operating Junction Temperature Range	-65 to +150	°C
Tstg	Storage Temperature Range	-65 to +200	°C

NOTE 1: Each Diode

NOTE 2: Pulsed: PW = 100ms max.; duty cycle $\leq 20\%$

NOTE 3: Derate at $2.4mA/^\circ C$ above $+25^\circ C$

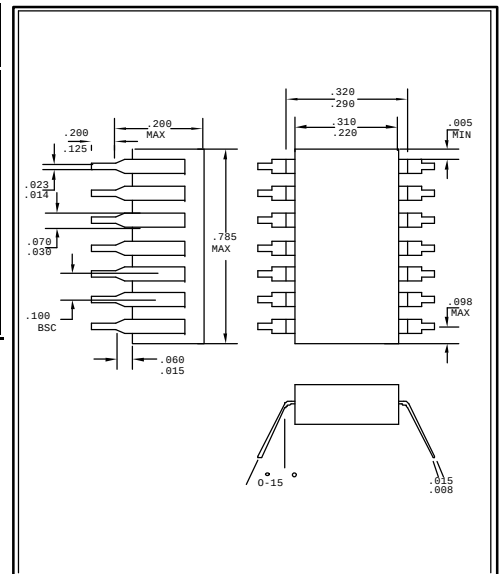
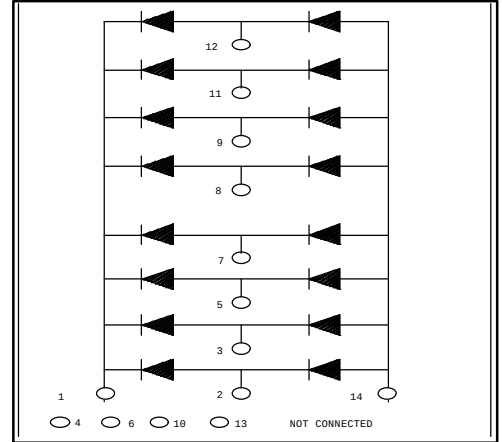
NOTE 4: Derate at $4.0mW/^\circ C$ above $+25^\circ C$

Electrical Characteristics (Per Diode) @ 25°C unless otherwise specified

Symbol	Parameter	Conditions	Min	Max	Unit
Vf1	Forward Voltage	If = 100mAdc *1		1	Vdc
Vf2	Forward Voltage	If = 500mAdc *1		1.5	Vdc
IR1	Reverse Current	VR = 40 Vdc		0.1	μA dc
Ct	Capacitance (pin to pin)	VR = 0 Vdc ; f = 1 MHz		8.0	pF
tfr	Forward Recovery Time	If = 500mAdc		40	ns
trr	Reverse Recovery Time	If = IR = 200mAdc, irr = 20mAdc, RL = 100 ohms		20	ns

NOTE 1: Pulsed: PW = 300us +/- 50us, duty cycle $\leq 2\%$, 90us after leading edge

Sertech reserves the right to make changes to any product design, specification or other information at any time without prior notice.



PACKAGE OUTLINE